

MITSUBISHI SEMICONDUCTOR <GaAs FET>

MGFC40V5964**5.9 ~ 6.4GHz BAND 10W INTERNALLY MATCHED GaAs FET****DESCRIPTION**

The MGFC40V3742 is an internally impedance-matched GaAs power FET especially designed for use in 5.9 ~ 6.4 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

FEATURES

- Class A operation
- Internally matched to 50(ohm) system
- High output power
P1dB = 10W (TYP.) @ f=5.9~6.4GHz
- High power gain
GLP = 10 dB (TYP.) @ f=5.9~6.4GHz
- High power added efficiency
P.A.E. = 30 % (TYP.) @ f=5.9~6.4GHz
- Low distortion [item -51]
IM3= -49 dBc(TYP.) @Po=29(dBm) S.C.L.

APPLICATION

- item 01 : 5.9~6.4 GHz band power amplifier
- item 51 : 5.9~6.4 GHz band digital radio communication

QUALITY GRADE

IG

RECOMMENDED BIAS CONDITIONS

- VDS = 10(V)
- ID = 2.4 (A)
- Rg = 50(ohm) Refer to Bias Procedure

ABSOLUTE MAXIMUM RATINGS (Ta=25 deg.C)

Symbol	Parameter	Ratings	Unit
VGDO	Gate to drain voltage	-15	V
VGSO	Gate to source voltage	-15	V
ID	Drain current	7.5	A
IGR	Reverse gate current	-20	mA
IGF	Forward gate current	42	mA
PT	Total power dissipation *1	42.8	W
Tch	Channel temperature	175	deg.C
Tstg	Storage temperature	-65 / +175	deg.C

*1 : Tc=25 deg.C

ELECTRICAL CHARACTERISTICS (Ta=25 deg.C)

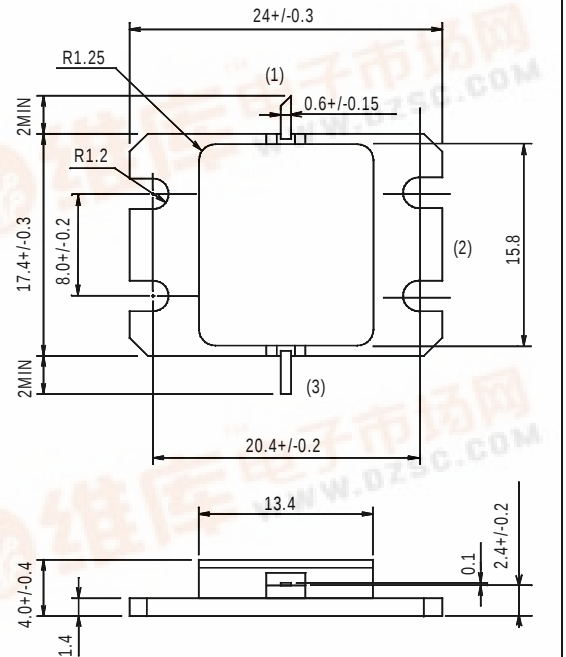
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IDSS	Saturated drain current	VDS=3V, VGS=0V	-	4.5	6	A
gm	Transconductance	VDS=3V, ID=2.2A	-	2	-	S
VGS(off)	Gate to source cut-off voltage	VDS=3V, ID=40mA	-2	-3	-4	V
P1dB	Output power at 1dB gain compression	VDS=10V, ID(RF off)=2.4A, f=5.9~6.4GHz	39.5	40.5	-	dBm
GLP	Linear power gain		8	10	-	dB
ID	Drain current		-	2.4	-	A
P.A.E.	Power added efficiency		-	30	-	%
IM3	3rd order IM distortion *1		-42	-49	-	dBc
Rth(ch-c)	Thermal resistance *2	Delta Vf method	-	3	3.5	deg.C/W

*1 : item -51, 2 tone test, Po=29dBm Single Carrier Level, f=6.4GHz, Delta f=10MHz

*2 : Channel to case

OUTLINE DRAWING

Unit: millimeters (inches)



GF-18

- (1): GATE
- (2): SOURCE (FLANGE)
- (3): DRAIN

< Keep safety first in your circuit designs! >

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MGFC40V5964**5.9 ~ 6.4GHz BAND 10W INTERNALLY MATCHED GaAs FET****Requests Regarding Safety Designs**

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